

# SKS B2 120 GDD 69/11 - A11 MA PB



SKiiP stack

## Absolute maximum ratings <sup>1)</sup>

Symbol	Conditions	Values	Unit
$I_{IN/OUT\ MAX}$	Maximum permanent input/output current	1 200	A <sub>RMS</sub>
$V_{IN/OUT\ MAX}$	Maximum output voltage	760	V <sub>AC</sub>
$V_{BUS\ MAX}$	Maximum DC Bus voltage	1 200	V <sub>DC</sub>
$F_{IN/OUT\ MAX}$	Inverter Output frequency	100	Hz
$F_{SW\ IN/OUT\ MAX}$	Maximum switching frequency	5	kHz

## Electrical characteristics: application example

T<sub>AMBIENT</sub>=40°C unless otherwise specified

Symbol	Conditions	min	typ	max	Unit
<b>AC phase Grid</b>					
$I_{OUT\ RATED}$	Rated output current		1 200		A <sub>RMS</sub>
$I_{OUT\ OVL}$	Overload output current		1 320		A <sub>RMS</sub>
$t_{OVL}$	Overload duration		60		s
$T_{OVL}$	Time between 2 overloads		10		min
$V_{OUT}$	Output voltage	620	690	760	V <sub>AC</sub>
$P_{OUT}$	Rated output power		1 430		kW
$F_{SW\ OUT}$	Inverter switching frequency		2		kHz
$F_{OUT}$	Output frequency		50		Hz
PF	Power factor		1		-
$P_{LOSS\ INV}^{2)}$	Losses at rated current		14090		W
$\eta^{2)}$	Efficiency at rated current		99		%

## AC phase Generator

$I_{IN\ RATED}$	Rated input current		1 200		A <sub>RMS</sub>
$V_{IN}$	Input voltage	620	690	760	V <sub>AC</sub>
$P_{IN}$	Rated input power		1430		kW
$F_{SW\ IN}$	Rectifier switching frequency		2		kHz
$F_{IN}$	Input frequency		50	100	Hz
PF	Power factor		-1		-
$P_{LOSS\ INV}^{2)}$	Losses at rated current		12880		W
$\eta^{2)}$	Efficiency at rated current		99		%

## DC Bus

$V_{BUS}$	Rated DC voltage applied to the capacitor bank		1 100		V <sub>DC</sub>
$V_{BUS\ MAX}$	Max DC voltage applied to the caps bank (max 30% of LTE)			1 200	V <sub>DC</sub>
$\tau_{d5\%}$	Discharge time of the capacitors (V <sub>DC</sub> < 60 V)		5		min
$C_{DC}$	Capacitor bank capacity		14		mF
LTE	Calculated LTE of the caps with forced air cooling		100		kh

## Stack Insulation

Crđ	Minimum creepage distance		11		mm
Clđ	Minimum clearance distance		9.4		mm
Visol	Chassis / power stage AC/DC (insulation test voltage DC, 5s)	-4 200		4 200	V <sub>DC</sub>
dv/dt	SKiiP driver only, secondary to primary side			75	kV/μs

## SEMISTACK for Renewable Energy - Size W2

4-Quadrant 3-phase IGBT converter

Ordering No. 08800589

Description SKS B2 120 GDD 69/11 - A11 MA PB

### Features

- Designed in regard to EN50178 and UL508C recommendations
- Designed for a 600 x 600 x 2000 mm cabinet
- Embedded SKiiP® Technology 3
- SKiiP 2403GB172-4DW, Trench 3 1700V IGBT, CAL3 diode
- Integrated current and temperature sensors
- Water cooling

### Typical Applications

- Wind generator converter
- Solar inverters

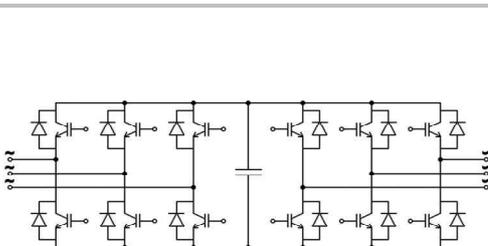
### Footnotes

<sup>1)</sup> Absolute maximum ratings are values not to be exceeded in any case and do not imply that the stack can operate in all these conditions taken together.

<sup>2)</sup> Fan consumption and losses in air included.

### REMARKS

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B6CI+B6CI

# SKS B2 120 GDD 69/11 - A11 MA PB



SKiiP stack

Environmental conditions		T <sub>AMBIENT</sub> =40°C unless otherwise specified			
Characteristics	Conditions	min	typ	max	Unit
<b>Climatic</b>					
Ambient temperature <sup>3)</sup>	Storage: IEC 60721-3-1, class 1K2 Transportation: IEC 60721-3-2, class 2K2	-25		60	°C
	Operation: IEC 60721-3-3, class 3K3 extended	-20		55	°C
Humidity	IEC 60721-3-3, class 3K3 no condensation no icing	5		85	%
<b>Mechanical</b>					
Installation altitude	without derating			1 000	m
Max installation altitude	with derating			4 000	m
Ingress protection	IEC 60529		IP00		-
Vibrations & Shocks	IEC 60721-3-2, Storage & transportation		2M1		-
	IEC 60721-3-3, in operation		3M3		-
Pollution degree	EN 50178		2		-
Mass	per stack		98		kg
	4-quadrant converter with DC-connection		198		kg
<b>Thermal</b>					
ΔV/Δt <sub>WATER</sub>	Water flow per stack	8	16	35	L/min
	Water flow per 4Q-converter	16	32	70	L/min
ΔP <sub>WATER</sub>	Pressure drop per stack, with male and female connectors, 50% glycol, 16 L/min		580		mbar
	Pressure drop per 4Q-converter, with male and female connectors, 50% glycol, 32 L/min		580		mbar
Water pressure	Rated water pressure per inverter		3		bar
Coolant type	Recommended coolant		50% glycol / 50% water		-
T <sub>INLET</sub>	Cooling water inlet temperature	-20	45	60	°C
Required cooling airflow <sup>3)</sup>	Airflow direction bottom to top on snubbers		1		m.s <sup>-1</sup>
V <sub>SUPPLY</sub>	Fan DC voltage supply	16	24	30	V <sub>DC</sub>
P <sub>FAN</sub> per fan	Fan power consumption at typical voltage supply		90		W
LTE	Capacitor DC fan lifetime expectancy (L10 method)		57		kh

## SEMISTACK for Renewable Energy - Size W2

4-Quadrant 3-phase IGBT converter

Ordering No. 08800589

Description SKS B2 120 GDD 69/11 - A11 MA PB

### Features

- Designed in regard to EN50178 and UL508C recommendations
- Designed for a 600 x 600 x 2000 mm cabinet
- Embedded SKiiP® Technology 3
- SKiiP 2403GB172-4DW, Trench 3 1700V IGBT, CAL3 diode
- Integrated current and temperature sensors
- Water cooling

### Typical Applications

- Wind generators (SG and DFIG)
- Solar Inverters

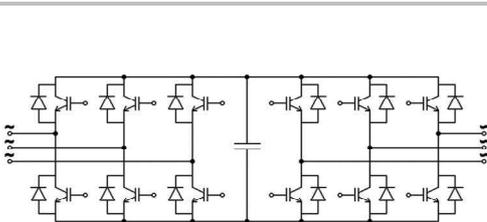
### Footnotes

<sup>3)</sup> the user shall ensure that the ambient air is sufficiently ventilated to avoid hot spots.

### REMARKS

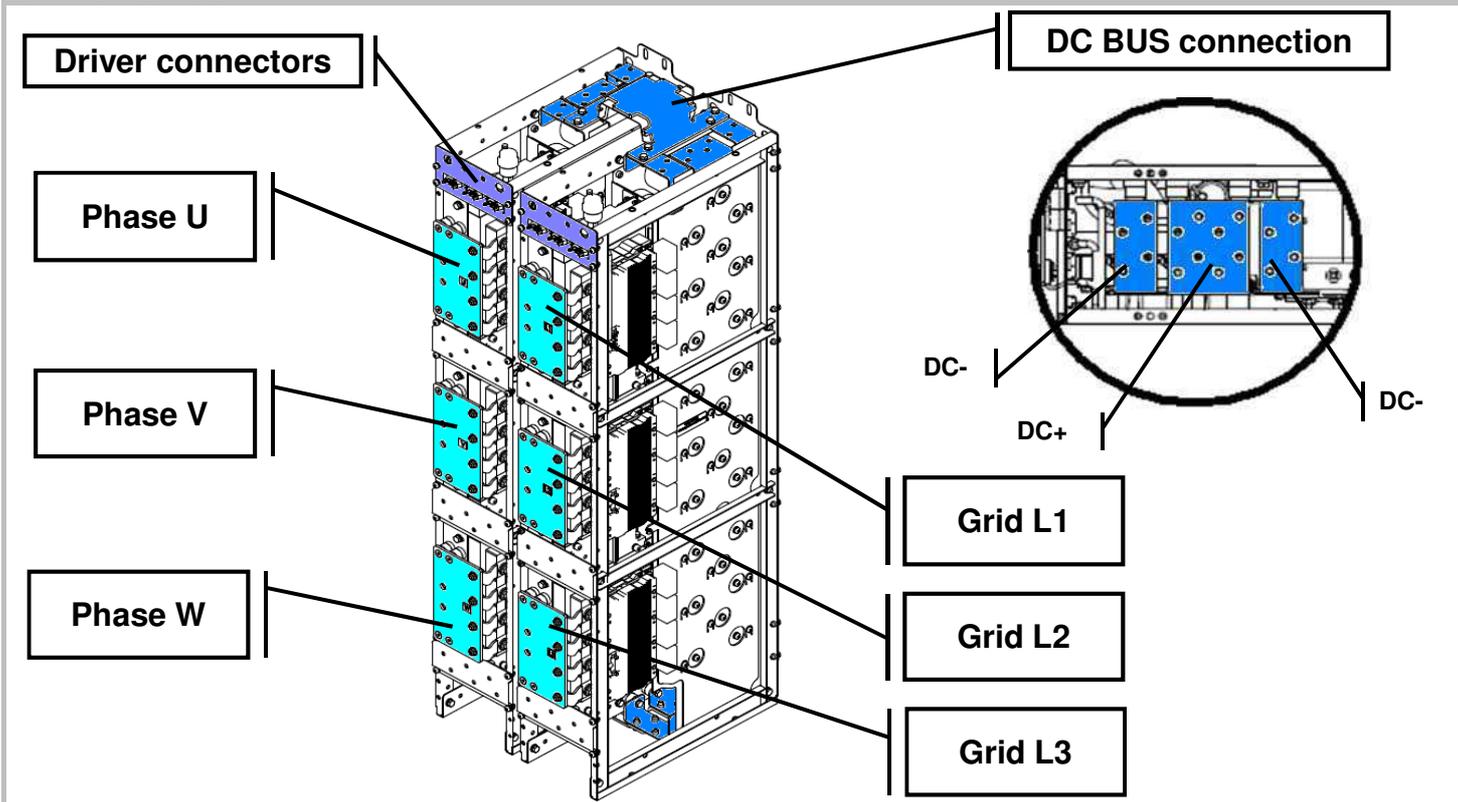
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Gate Driver Characteristics		T <sub>AMBIENT</sub> =25°C unless otherwise specified			
Symbol	Conditions	min	typ	max	Unit
<b>Gate Driver / controller data</b>					
V <sub>S</sub>	supply voltage non stabilized	13	24	30	V
I <sub>S</sub>	V <sub>S</sub> = 24 V, F <sub>SW</sub> in kHz, I <sub>RMS</sub> in A	330 + 55×F <sub>sw</sub> + 0.00035×I <sub>RMS</sub> <sup>2</sup>			mA
V <sub>IT+</sub>	input threshold voltage HIGH	12.3			V
V <sub>IT-</sub>	input threshold voltage LOW	4.6			V
R <sub>IN</sub>	Input resistance	10			kΩ
C <sub>IN</sub>	Input capacitance	1			nF
<b>Measurement &amp; protection</b>					
I <sub>analog</sub>	Analogue current signal	250			A.V <sup>-1</sup>
I <sub>TRIP SC</sub>	Over current trip level (I <sub>analog</sub> OUT=10V)	2450	2 500	2550	A <sub>PEAK</sub>
CMN_TMP	Analogue temperature signal Th < 80°C	min	17 + 10.3×CMN_TMP		°C
		typ	19 + 10.5×CMN_TMP		°C
		max	20 + 10.5×CMN_TMP		°C
CMN_TMP	Analogue temperature signal Th > 80°C	min	26 + 8.8×CMN_TMP		°C
		typ	28 + 8.8×CMN_TMP		°C
		max	30 + 8.9×CMN_TMP		°C
T <sub>TRIP</sub>	Over temperature protection	110	115	120	°C

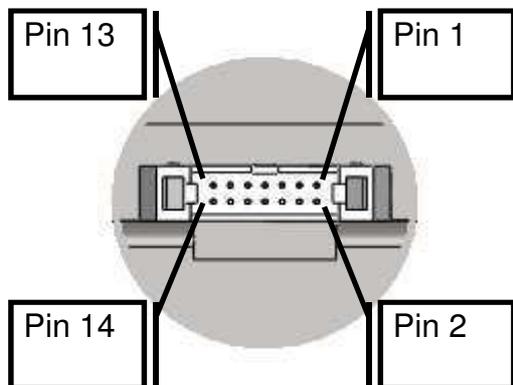
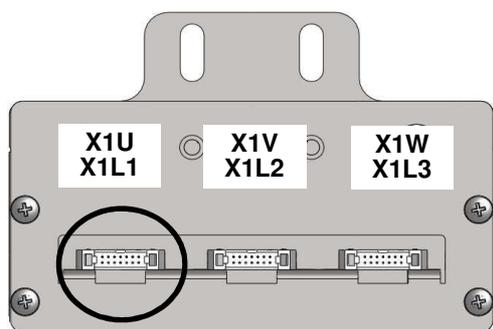


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Electrical connection



Drive connector assignment



HE10-14 male connector

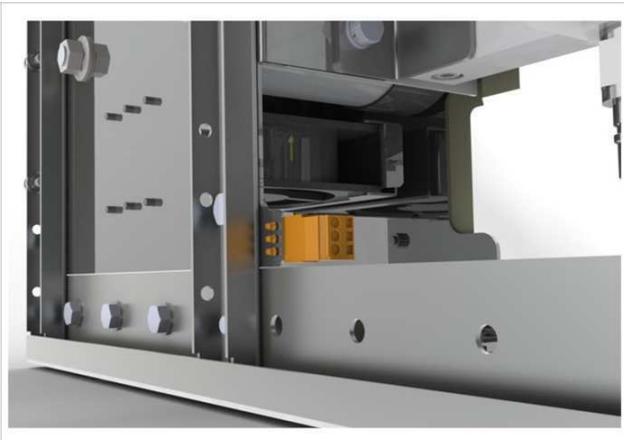
X1U, X1V, X1W, X1L1, X1L2, X1L3

Pin	Signal	Remark
1	Shield	
2	BOT IN (2)	positive 15V CMOS logic; 10 kΩ impedance, don't connect when using fiber optic
3	ERROR OUT (1)	LOW = NO ERROR; open Collector Output; max. 30 V / 15 mA don't connect when using fiber optic, propagation delay 1 μs min. pulsewidth error-memory-reset 9 μs
4	TOP IN (2)	positive 15V CMOS logic; 10 kΩ impedance don't connect when using fiber optic
5	Overtemp. OUT (1)	LOW = NO ERROR = ̸DCB < 115 + 5°C open collector Output; max. 30 V / 15 mA „low“ output voltage < 0,6 V „high“ output voltage max. 30 V
6	+ 24 VDC IN	24 VDC (SKiiP 2: 20 - 30 V, SKiiP 3: 13 - 30 V)
7	+ 24 VDC IN	don't supply with 24V, when using +15 VDCIN supply voltage monitoring threshold 19,5 V
8	+15 Vdc OUT	max. 50 mA auxiliary power supply when
9	+15 Vdc OUT	SKiiP system is supplied via pin 6/7
10	GND	GND for power supply and
11	GND	GND for digital signals
12	Temp. analog OUT	max output current 5mA
13	GND aux	reference for analog output signals
14	I analog OUT	SKiiP 3 with Al2O3 ceramic substrate current actual value 8,0 V ⇔ 100 % IC @ 25 °C overcurrent trip level 10 V ⇔ 125 % IC @ 25 °C current value > 0 ⇔ SKiiP system is source current value < 0 ⇔ SKiiP system is sink SKiiP 3 with AlN ceramic substrate: refer to corresponding datasheet

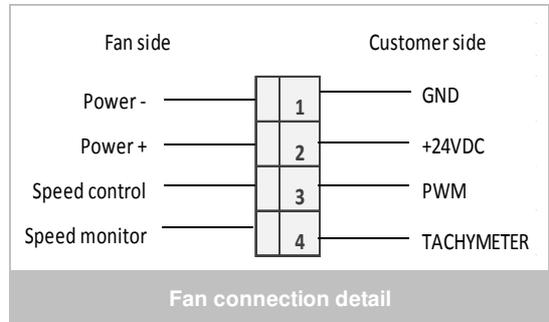
1) Open collector output, external pull up resistor necessary

2) „high“ (max) 12,3 V, „low“ (min) 4,6 V; SKiiP 3: 1 nF capacitance added signal to GND

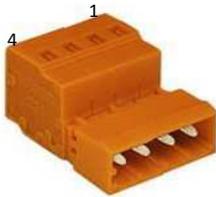
DC fan connection



Fan connection detail

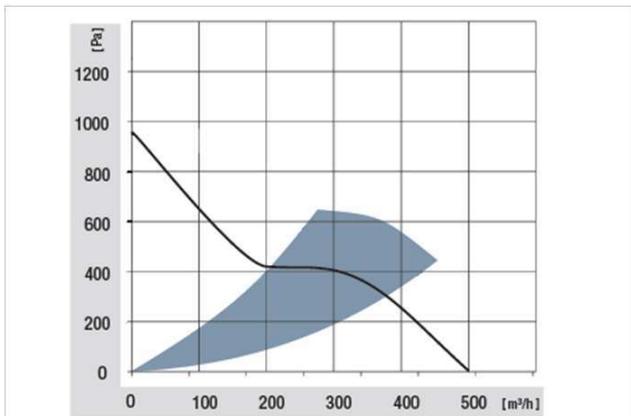


Fan connection detail

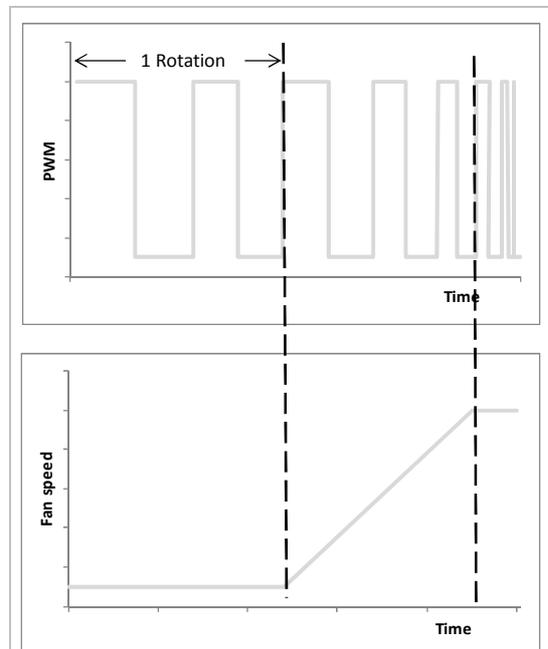


Pin	Designation
1	GND
2	+24VDC
3	PWM
4	MONITOR

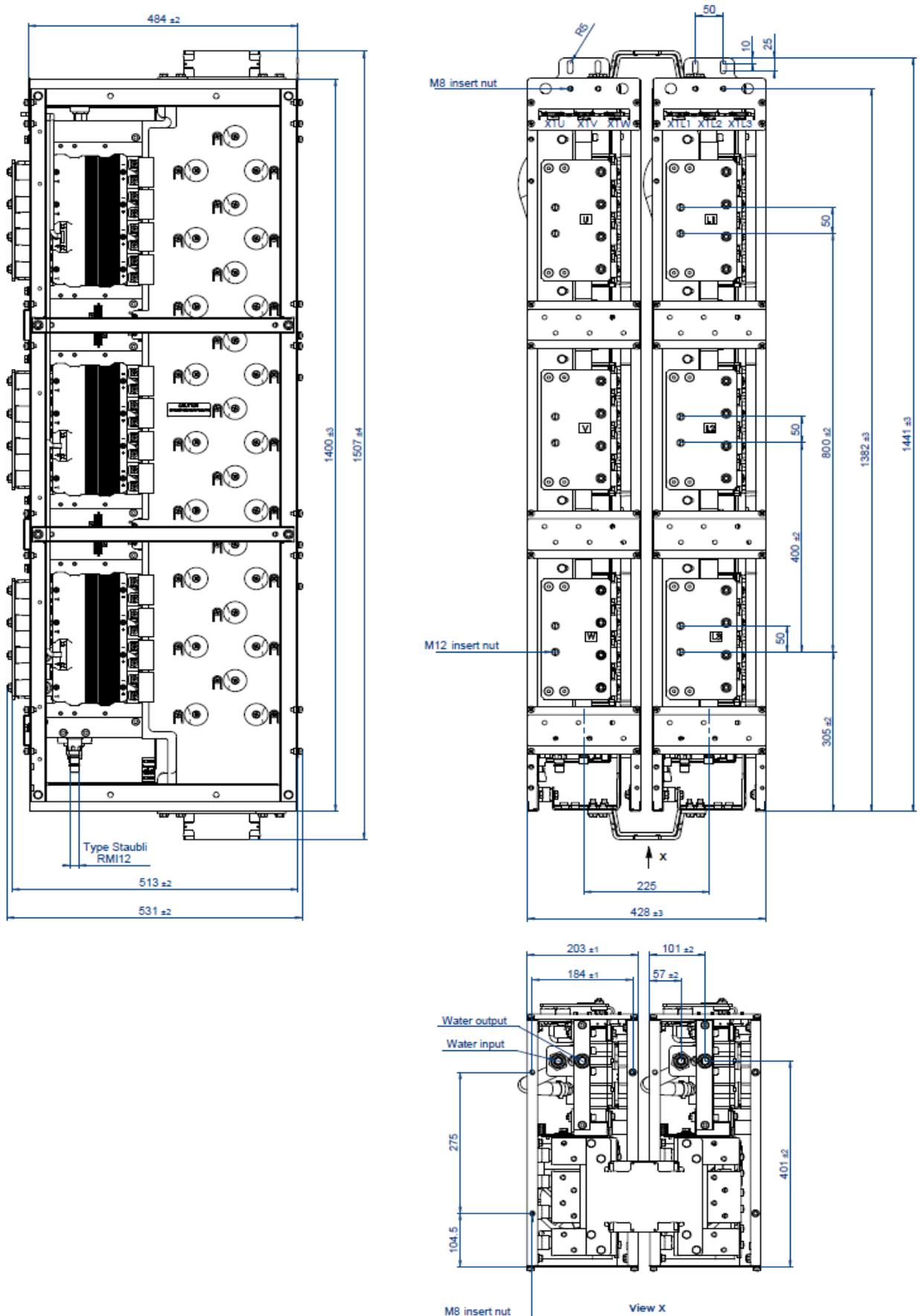
DC fan speed control



Characteristic pressure drop vs air flow

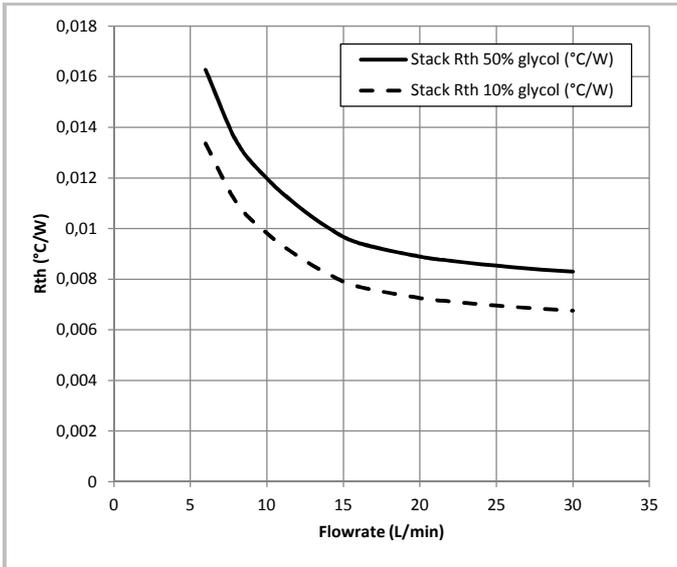


Speed control behavior

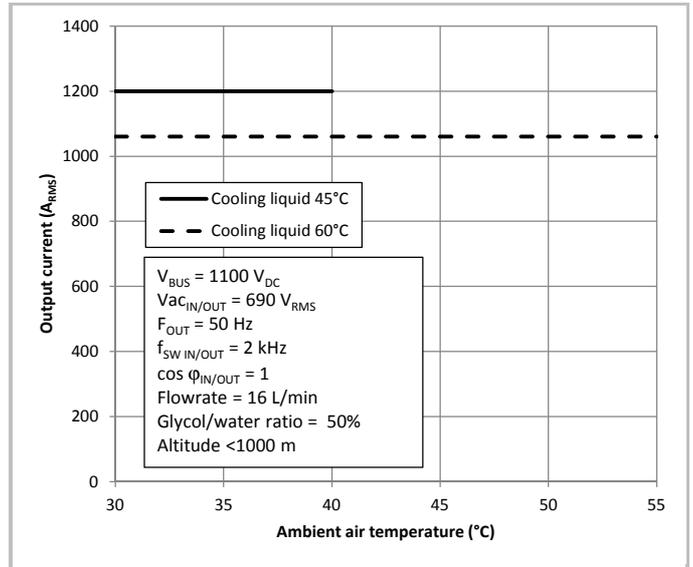


Dimensions

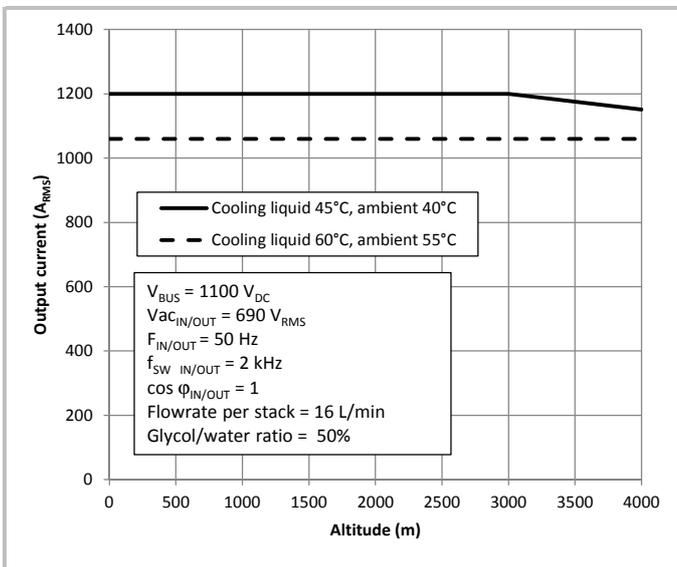
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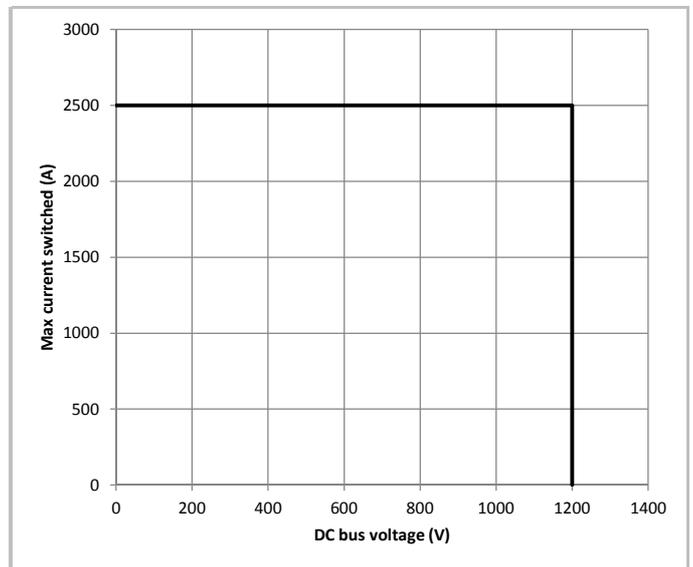
$R_{th_{SINK-WATER}}$ (stack) vs. Liquid Flow



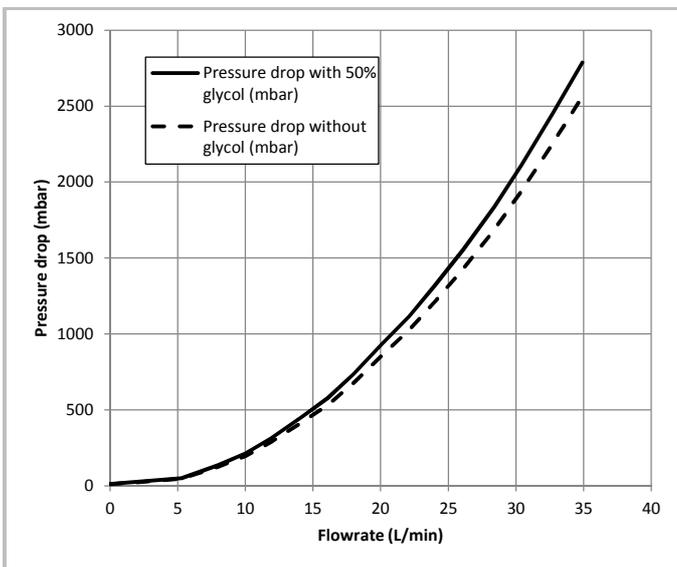
Permanent Output Current vs. Ambient Temperature



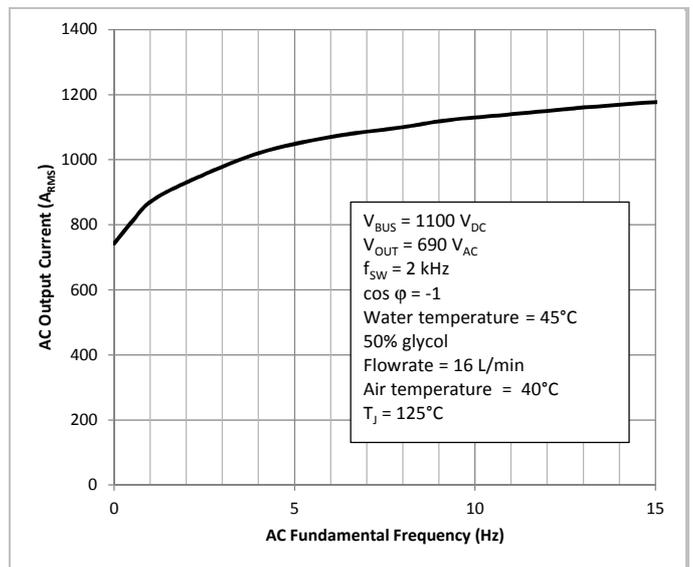
Permanent Output Current vs. Altitude



Safe Operating Area



Pressure Drop vs. Flowrate (per stack)



Input Current vs. Input frequency (generator side)